# NSN 5961-00-488-7376

Transistor - Page 1 of 1



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**Inclosure Material:** 

Metal

**Overall Length:** 

0.375 inches

## **Overall Diameter:**

0.875 inches

## **Mounting Facility Quantity:**

2

## Internal Configuration:

Junction contact

## Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Unthreaded hole

Features Provided:

#### Hermetically sealed case

Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

40.0 breakdown voltage, collector-to-emitter, base open and 40.0 collector to base voltage, dc

## **Current Rating Per Characteristic:**

Between 1.00 amperes source cutoff current and 5.00 amperes source cutoff current

## Power Rating Per Characteristic:

87.5 watts small-signal input power, common-collector absolute

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

## **Special Features:**

Junction pattern arrangement: pnp

## **Terminal Type And Quantity:**

2 uninsulated wire lead and 1 case

## **Specification Data:**

80131-release5443 professional/industrial association specification

#### Shelf Life:

N/a

## Unit Of Measure:

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## Demilitarization:

No

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